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# FDP42AN15A0

## N-Channel PowerTrench® MOSFET

150 V, 35 A, 42 mΩ

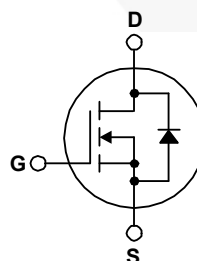
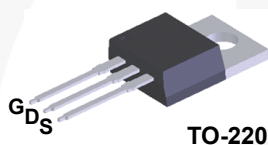
### Features

- $R_{DS(on)} = 36 \text{ m}\Omega$  (Typ.) @  $V_{GS} = 10 \text{ V}$ ,  $I_D = 12 \text{ A}$
- $Q_{G(tot)} = 33 \text{ nC}$  (Typ.) @  $V_{GS} = 10 \text{ V}$
- Low Miller Charge
- Low  $Q_{rr}$  Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)

### Applications

- Consumer Appliances
- Synchronous Rectification
- Uninterruptible Power Supply
- Micro Solar Inverter

Formerly developmental type 82864



### MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	FDP42AN15A0	Unit
$V_{DSS}$	Drain to Source Voltage	150	V
$V_{GS}$	Gate to Source Voltage	$\pm 20$	V
$I_D$	Drain Current		
	Continuous ( $T_C = 25^\circ\text{C}$ , $V_{GS} = 10\text{V}$ )	35	A
	Continuous ( $T_C = 100^\circ\text{C}$ , $V_{GS} = 10\text{V}$ )	24	
	Continuous ( $T_{amb} = 25^\circ\text{C}$ , $V_{GS} = 10\text{V}$ , with $R_{\theta JA} = 43^\circ\text{C/W}$ )	5	A
	Pulsed	Figure 4	A
$E_{AS}$	Single Pulse Avalanche Energy (Note 1)	90	mJ
$P_D$	Power dissipation	150	W
	Derate above $25^\circ\text{C}$	1.00	W/ $^\circ\text{C}$
$T_J, T_{STG}$	Operating and Storage Temperature	-55 to 175	$^\circ\text{C}$

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.0	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62	$^\circ\text{C/W}$

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP42AN15A0	FDP42AN15A0	TO-220	Tube	N/A	50 units

## Electrical Characteristics $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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### Off Characteristics

$B_{V_{DS}}$	Drain to Source Breakdown Voltage	$I_D = 250\mu\text{A}$ , $V_{GS} = 0\text{V}$	150	-	-	V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 120\text{V}$ $V_{GS} = 0\text{V}$ $T_C = 150^\circ\text{C}$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	$\pm 100$	nA

### On Characteristics

$V_{GS(TH)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 250\mu\text{A}$	2	-	4	V
$r_{DS(ON)}$	Drain to Source On Resistance	$I_D = 12\text{A}$ , $V_{GS} = 10\text{V}$	-	0.036	0.042	$\Omega$
		$I_D = 6\text{A}$ , $V_{GS} = 6\text{V}$	-	0.040	0.060	
		$I_D = 12\text{A}$ , $V_{GS} = 10\text{V}$ , $T_J = 175^\circ\text{C}$	-	0.090	0.107	

### Dynamic Characteristics

$C_{ISS}$	Input Capacitance	$V_{DS} = 25\text{V}$ , $V_{GS} = 0\text{V}$ , $f = 1\text{MHz}$	-	2150	-	pF
$C_{OSS}$	Output Capacitance		-	225	-	pF
$C_{RSS}$	Reverse Transfer Capacitance		-	45	-	pF
$Q_{g(TOT)}$	Total Gate Charge at 10V	$V_{GS} = 0\text{V}$ to 10V	-	30	39	nC
$Q_{g(TH)}$	Threshold Gate Charge	$V_{GS} = 0\text{V}$ to 2V	-	4.2	5.4	nC
$Q_{gs}$	Gate to Source Gate Charge	$V_{DD} = 75\text{V}$ $I_D = 12\text{A}$ $I_g = 1.0\text{mA}$	-	9.5	-	nC
$Q_{gs2}$	Gate Charge Threshold to Plateau		-	5.3	-	nC
$Q_{gd}$	Gate to Drain "Miller" Charge		-	6.9	-	nC

### Switching Characteristics ( $V_{GS} = 10\text{V}$ )

$t_{ON}$	Turn-On Time	$V_{DD} = 75\text{V}$ , $I_D = 12\text{A}$ $V_{GS} = 10\text{V}$ , $R_{GS} = 7.5\Omega$	-	-	46	ns
$t_{d(ON)}$	Turn-On Delay Time		-	11	-	ns
$t_r$	Rise Time		-	19	-	ns
$t_{d(OFF)}$	Turn-Off Delay Time		-	27	-	ns
$t_f$	Fall Time		-	23	-	ns
$t_{OFF}$	Turn-Off Time		-	-	74	ns

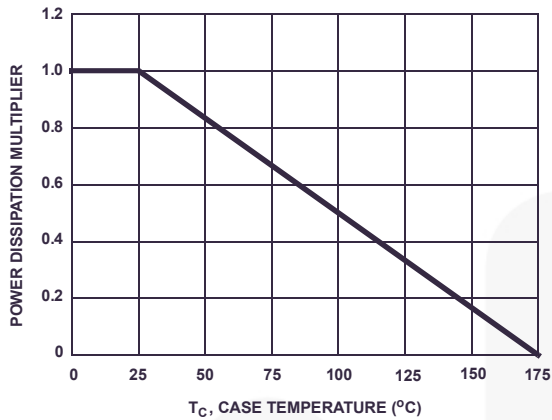
### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Voltage	$I_{SD} = 12\text{A}$	-	-	1.25	V
		$I_{SD} = 6\text{A}$	-	-	1.0	V
$t_{rr}$	Reverse Recovery Time	$I_{SD} = 12\text{A}$ , $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	82	ns
$Q_{RR}$	Reverse Recovered Charge	$I_{SD} = 12\text{A}$ , $dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	204	nC

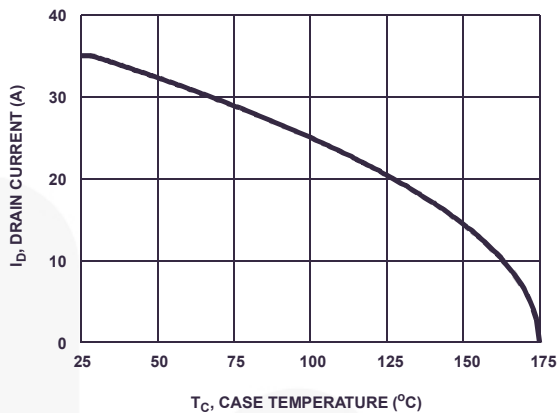
#### Notes:

1: Starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.2\text{mH}$ ,  $I_{AS} = 30\text{A}$ .

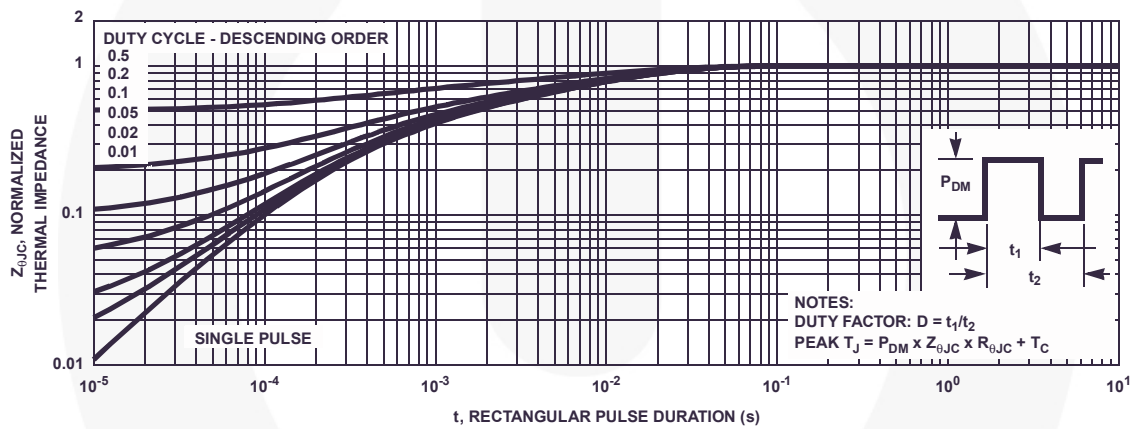
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



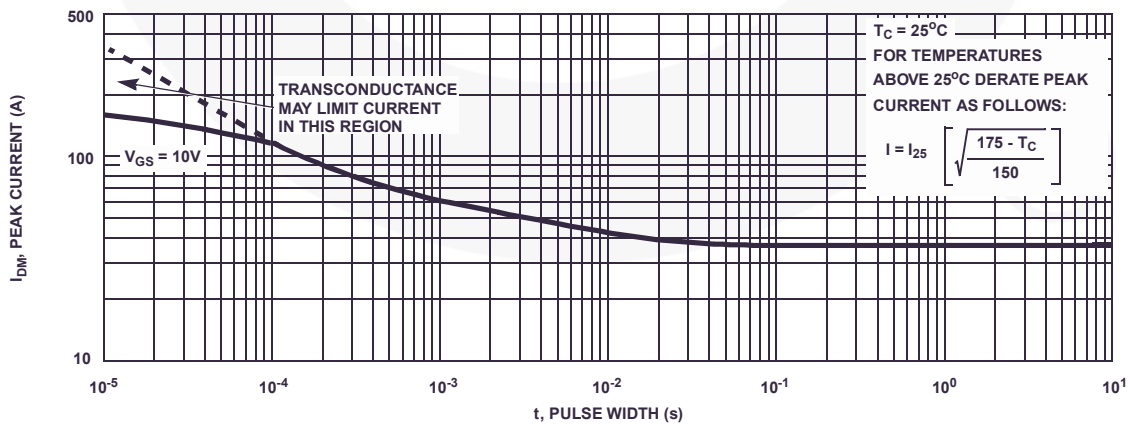
**Figure 1. Normalized Power Dissipation vs Ambient Temperature**



**Figure 2. Maximum Continuous Drain Current vs Case Temperature**

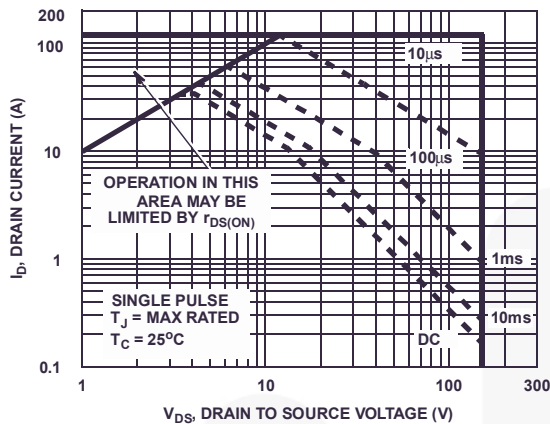


**Figure 3. Normalized Maximum Transient Thermal Impedance**

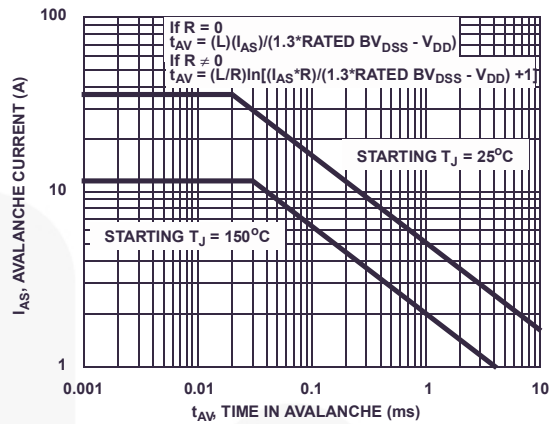


**Figure 4. Peak Current Capability**

**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

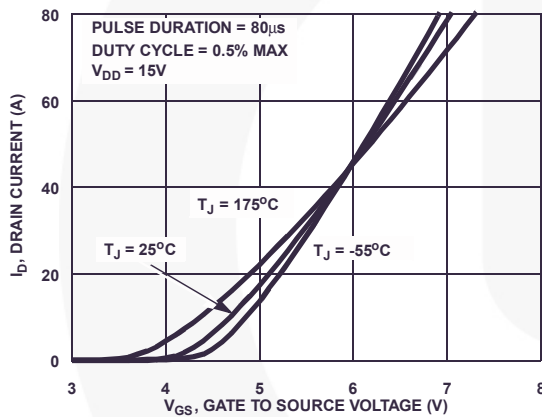


**Figure 5. Forward Bias Safe Operating Area**

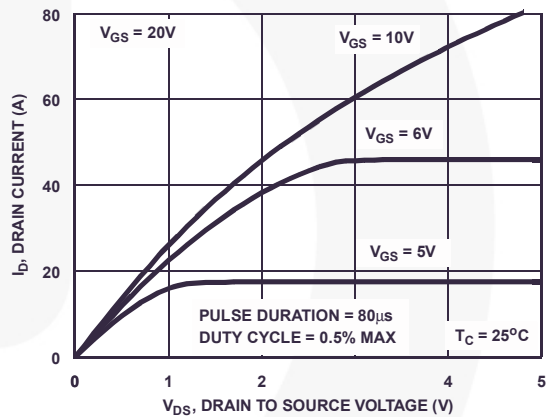


NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

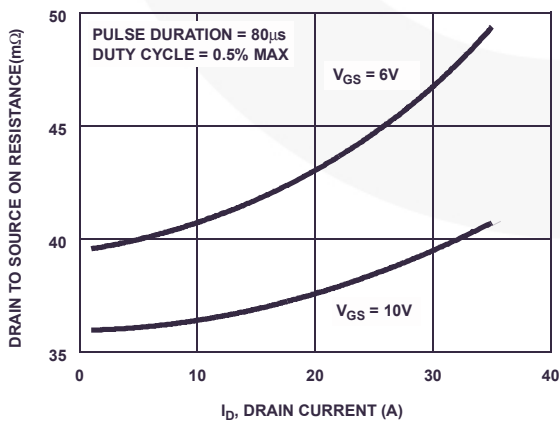
**Figure 6. Unclamped Inductive Switching Capability**



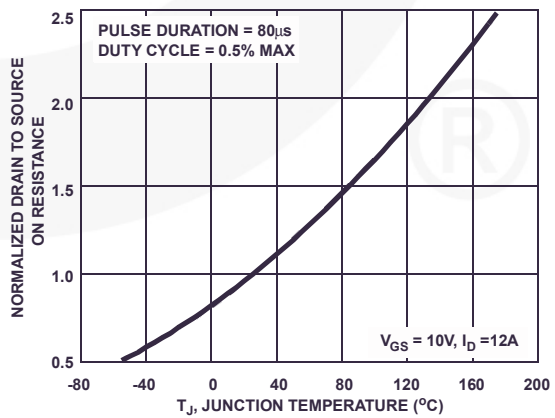
**Figure 7. Transfer Characteristics**



**Figure 8. Saturation Characteristics**

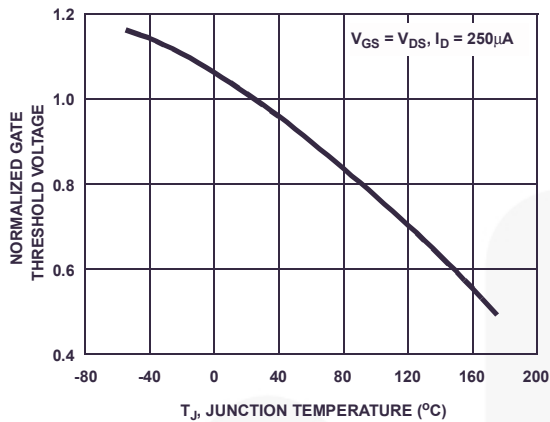


**Figure 9. Drain to Source On Resistance vs Drain Current**

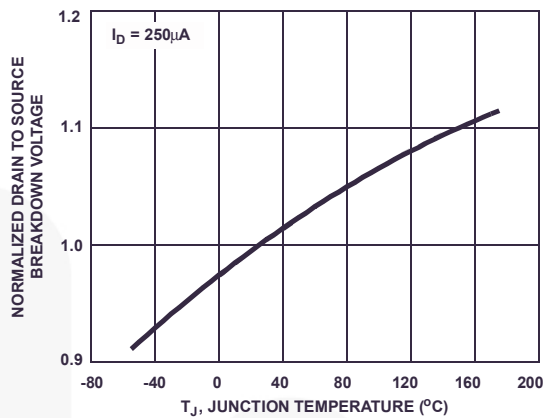


**Figure 10. Normalized Drain to Source On Resistance vs Junction Temperature**

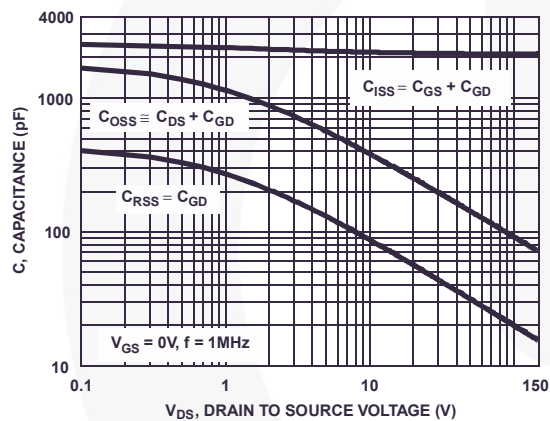
**Typical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted



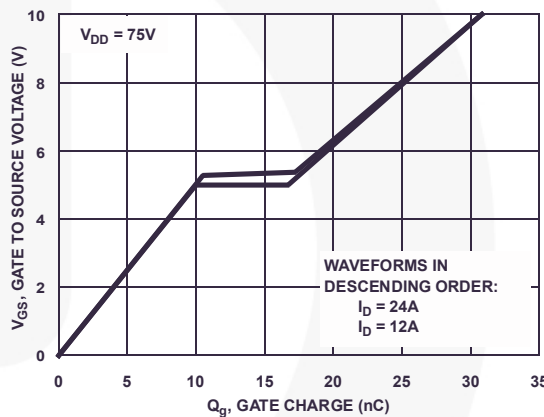
**Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature**



**Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature**



**Figure 13. Capacitance vs Drain to Source Voltage**



**Figure 14. Gate Charge Waveforms for Constant Gate Current**

### Test Circuits and Waveforms

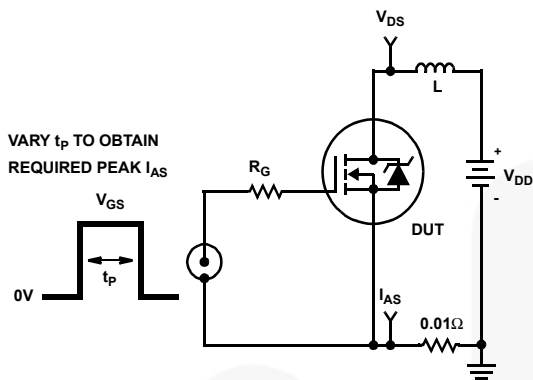


Figure 15. Unclamped Energy Test Circuit



Figure 16. Unclamped Energy Waveforms

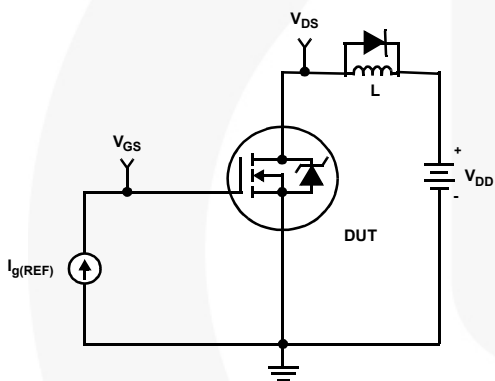


Figure 17. Gate Charge Test Circuit



Figure 18. Gate Charge Waveforms



Figure 19. Switching Time Test Circuit



Figure 20. Switching Time Waveforms







### SPICE Thermal Model

REV 23 June 11, 2002

FDB42AN15A0\_Thermal

```

CTHERM1 TH 6 2e-3
CTHERM2 6 5 4.5e-3
CTHERM3 5 4 7e-3
CTHERM4 4 3 3e-2
CTHERM5 3 2 4e-2
CTHERM6 2 TL 8.5e-1
    
```

```

R THERM1 TH 6 6.2e-2
R THERM2 6 5 8.2e-2
R THERM3 5 4 9.2e-2
R THERM4 4 3 9.7e-2
R THERM5 3 2 0.2
R THERM6 2 TL 0.22
    
```

### SABER Thermal Model

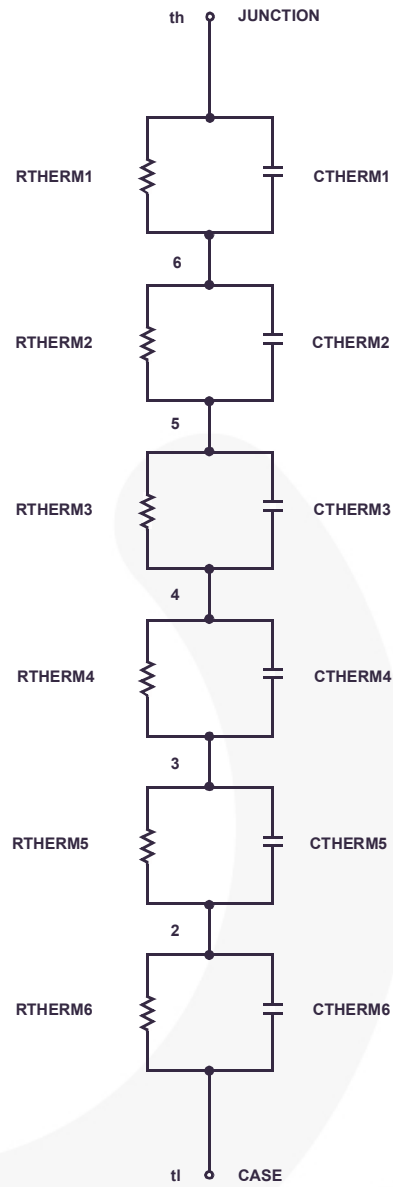
SABER thermal model FDB42AN15A0\_Thermal  
 template thermal\_model th tl  
 thermal\_c th, tl

```

{
ctherm.ctherm1 th 6 =2e-3
ctherm.ctherm2 6 5 =4.5e-3
ctherm.ctherm3 5 4 =7e-3
ctherm.ctherm4 4 3 =3e-2
ctherm.ctherm5 3 2 =4e-2
ctherm.ctherm6 2 tl =8.5e-1
    
```

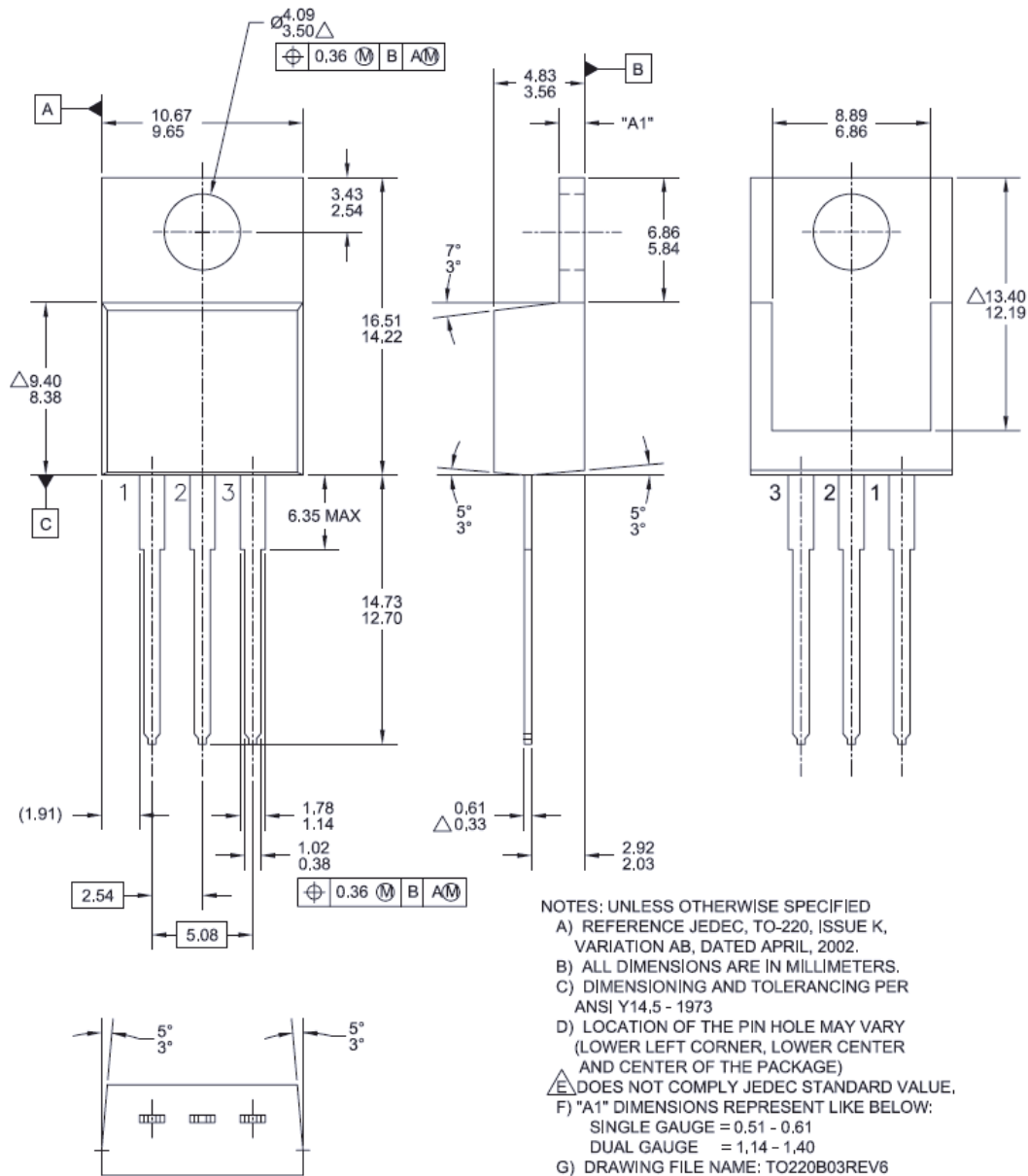
```

rtherm.rtherm1 th 6 =6.2e-2
rtherm.rtherm2 6 5 =8.2e-2
rtherm.rtherm3 5 4 =9.2e-2
rtherm.rtherm4 4 3 =9.7e-2
rtherm.rtherm5 3 2 =0.2
rtherm.rtherm6 2 tl =0.22}
    
```



## Mechanical Dimensions

### TO-220 3L



**Figure 21. TO-220, Molded, 3Lead, Jedec Variation AB**

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Dimension in Millimeters



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| CTL™                     | GTO™  | TinyPower™       |
| Current Transfer Logic™  | IntelliMAX™                                     | TinyPWM™         |
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| Dual Cool™               | Marking Small Speakers Sound Louder and Better™ | TranSiC™         |
| EcoSPARK®                | MegaBuck™                                       | TriFault Detect™ |
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| FACT®                    | MotionMax™                                      | UniFET™          |
| FAST®                    | mWSaver®  | VCX™             |
| FastvCore™               | OptoHiT™  | VisualMax™       |
| FETBench™                | OPTOLOGIC®                                      | VoltagePlus™     |
| FPS™                     | OPTOPLANAR®                                     | XS™              |
|                          |   |                  |
|                          | PowerTrench®                                    |                  |
|                          | PowerXS™  |                  |
|                          | Programmable Active Droop™                      |                  |
|                          | QFET®   |                  |
|                          | QS™   |                  |
|                          | Quiet Series™                                   |                  |
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